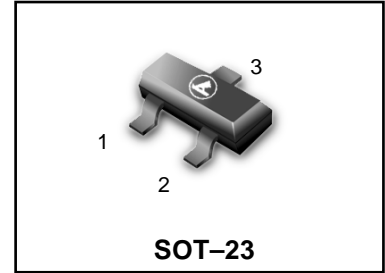


General Purpose Transistors

NPN Silicon

- We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

LBC817-16LT1G
LBC817-25LT1G
LBC817-40LT1G
S-LBC817-16LT1G
S-LBC817-25LT1G
S-LBC817-40LT1G

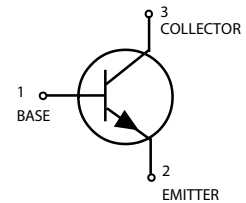


MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	45	V
Collector–Base Voltage	V_{CBO}	50	V
Emitter–Base Voltage	V_{EBO}	5.0	V
Collector Current — Continuous	I_C	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR– 5 Board, (1) $T_A = 25^\circ\text{C}$	P_D	225	mW
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	P_D	300	mW
Derate above 25°C		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$



DEVICE MARKING

LBC817-16LT1G = 6A; LBC817-25LT1G = 6B; LBC817-40LT1G = 6C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = 10\text{ mA}$)	$V_{(BR)CEO}$	45	—	—	V
Collector–Emitter Breakdown Voltage ($V_{EB} = 0, I_C = 10\ \mu\text{A}$)	$V_{(BR)CES}$	50	—	—	V
Emitter–Base Breakdown Voltage ($I_E = 1.0\ \mu\text{A}$)	$V_{(BR)EBO}$	5.0	—	—	V
Collector Cutoff Current ($V_{CB} = 20\text{ V}$)	I_{CBO}	—	—	100	nA
($V_{CB} = 20\text{ V}, T_A = 150^\circ\text{C}$)		—	—	5.0	μA

1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
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ON CHARACTERISTICS

DC Current Gain ($I_C = 100\text{ mA}$, $V_{CE} = 1.0\text{ V}$)	h_{FE}	100	—	250	
	LBC817-16	160	—	400	
	LBC817-25	250	—	600	
	LBC817-40	40	—	—	
Collector-Emitter Saturation Voltage ($I_C = 500\text{ mA}$, $I_B = 50\text{ mA}$)	$V_{CE(sat)}$	—	—	0.7	V
Base-Emitter On Voltage ($I_C = 500\text{ mA}$, $V_{CE} = 1.0\text{ V}$)	$V_{BE(on)}$	—	—	1.2	V

SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product ($I_C = 10\text{ mA}$, $V_{CE} = 5.0\text{ V}_{dc}$, $f = 100\text{ MHz}$)	f_T	100	—	—	MHz
Output Capacitance ($V_{CB} = 10\text{ V}$, $f = 1.0\text{ MHz}$)	C_{obo}	—	10	—	pF

ORDERING INFORMATION

Device	Marking	Shipping
LBC817-16LT1G	6A	3000/Tape&Reel
LBC817-16LT3G	6A	10000/Tape&Reel
LBC817-25LT1G	6B	3000/Tape&Reel
LBC817-25LT3G	6B	10000/Tape&Reel
LBC817-40LT1G	6C	3000/Tape&Reel
LBC817-40LT3G	6C	10000/Tape&Reel

LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G

TYPICAL CHARACTERISTICS – LBC817-16LT1G

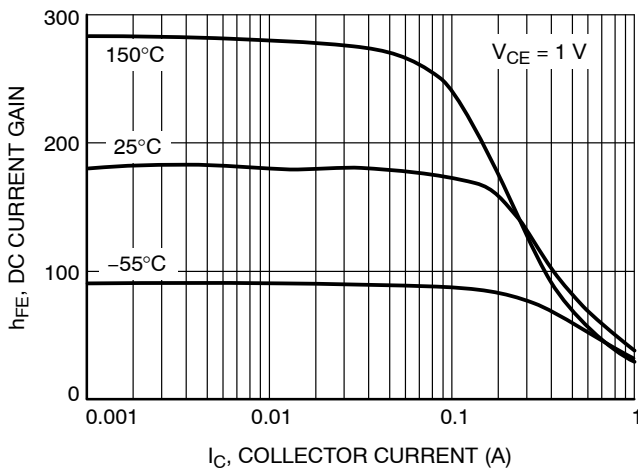


Figure 1. DC Current Gain vs. Collector Current

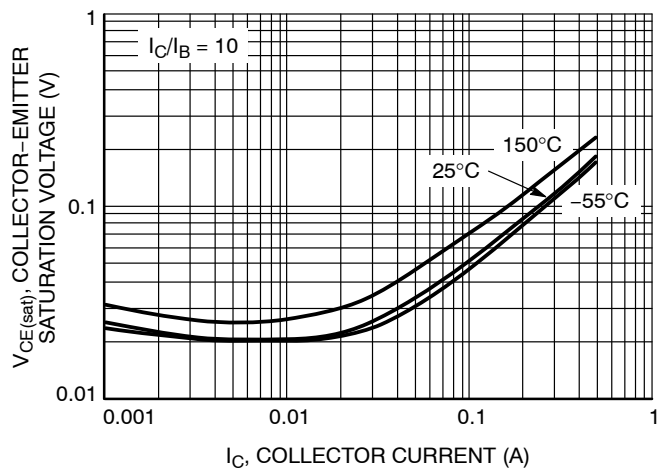


Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

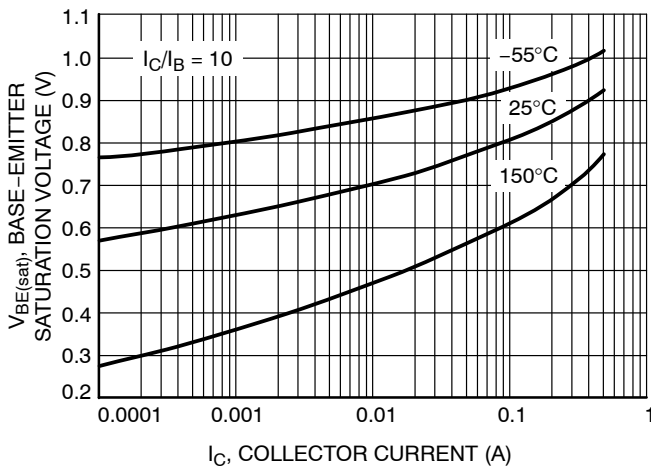


Figure 3. Base Emitter Saturation Voltage vs. Collector Current

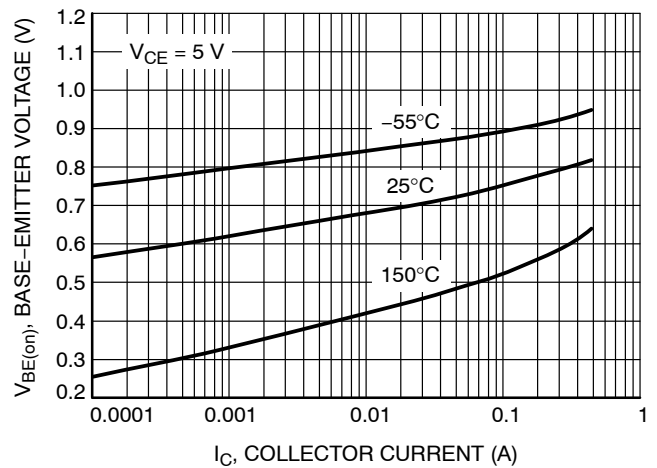


Figure 4. Base Emitter Voltage vs. Collector Current

LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G

TYPICAL CHARACTERISTICS - LBC817-16LT1G

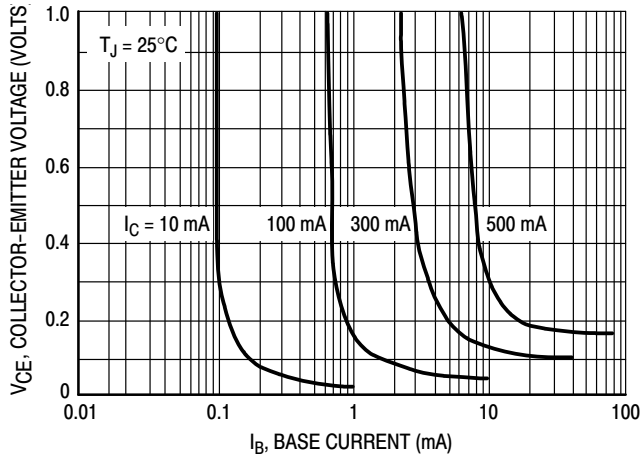


Figure 5. Saturation Region

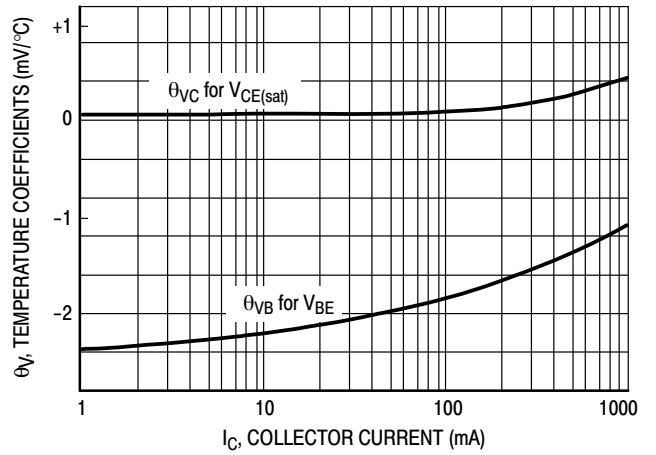


Figure 6. Temperature Coefficients

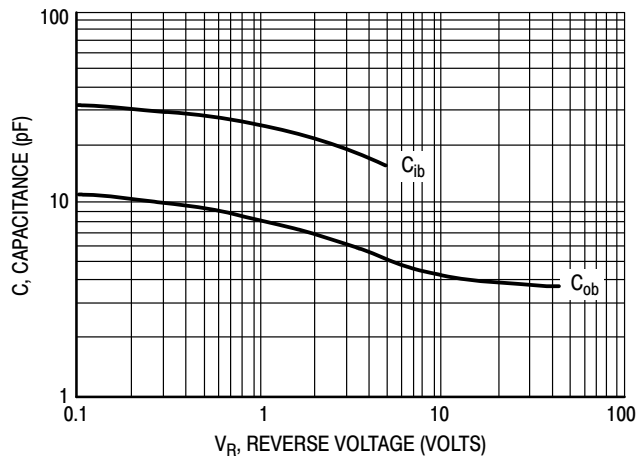
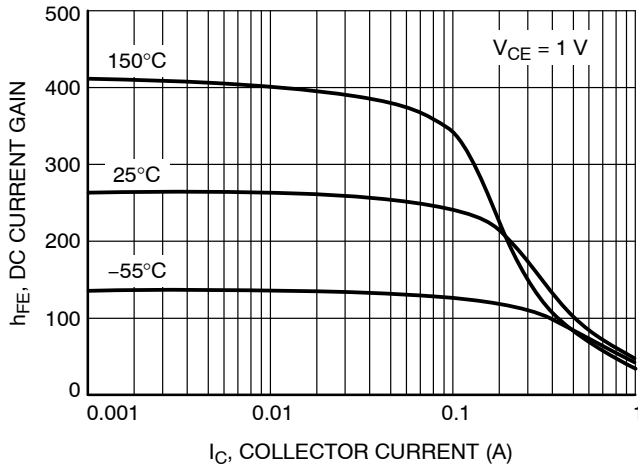
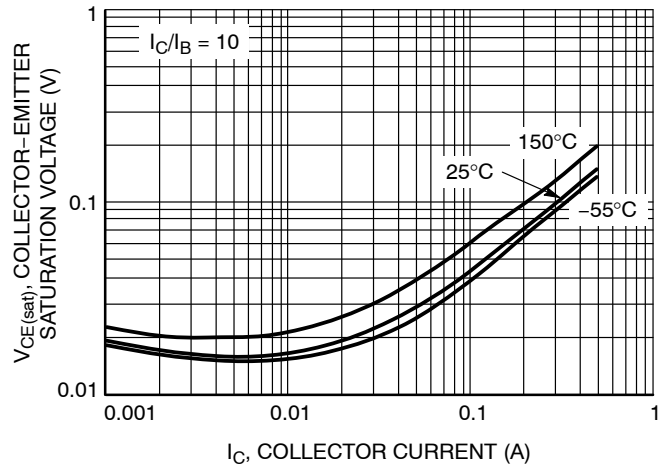
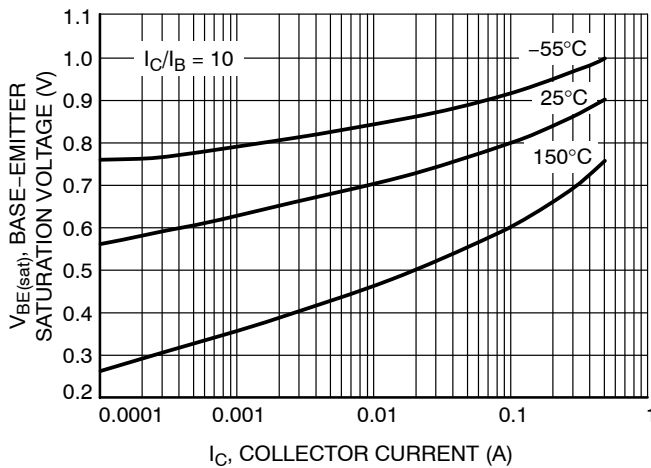
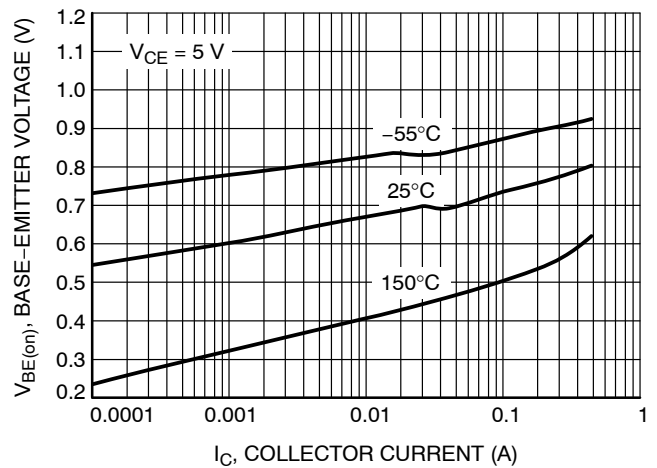
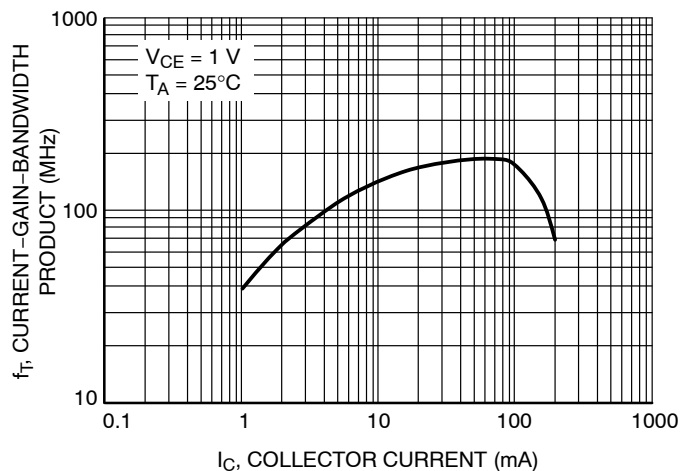


Figure 7. Capacitances

**LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G**
TYPICAL CHARACTERISTICS – LBC817-25LT1G

Figure 8. DC Current Gain vs. Collector Current

Figure 9. Collector Emitter Saturation Voltage vs. Collector Current

Figure 10. Base Emitter Saturation Voltage vs. Collector Current

Figure 11. Base Emitter Voltage vs. Collector Current

Figure 12. Current Gain Bandwidth Product vs. Collector Current

LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
 S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G

TYPICAL CHARACTERISTICS - LBC817-25LT1G

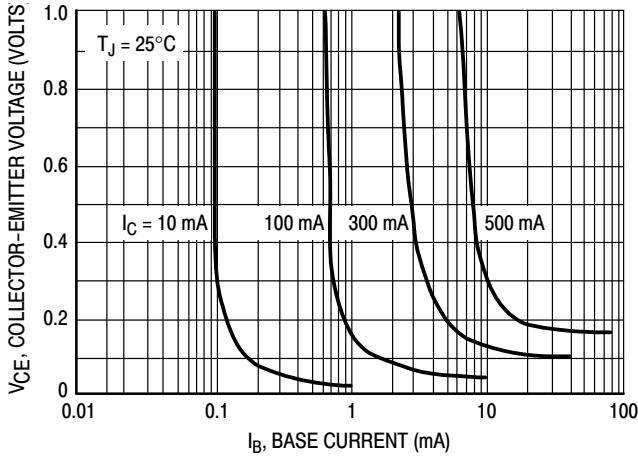


Figure 13. Saturation Region

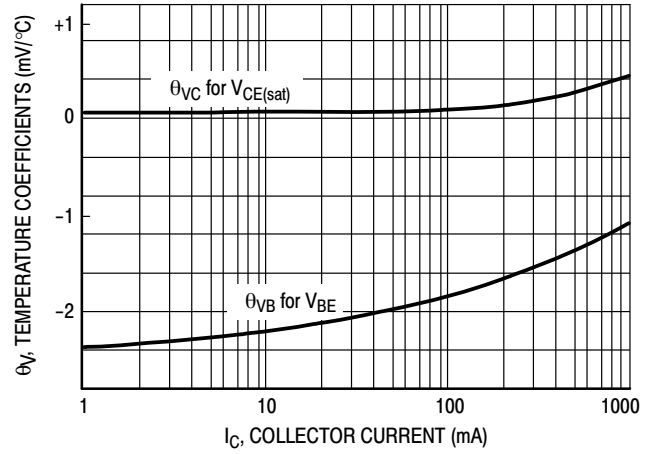


Figure 14. Temperature Coefficients

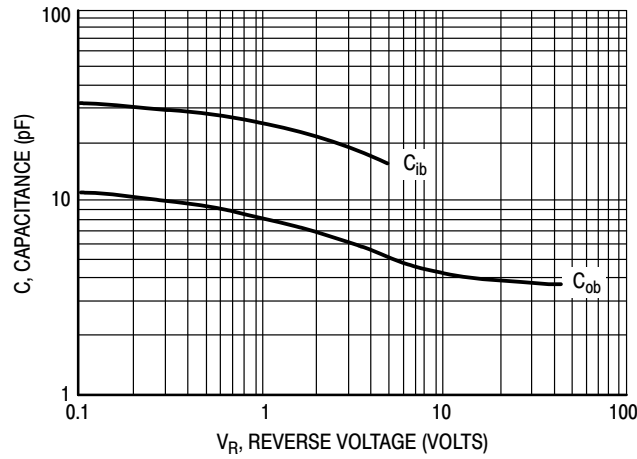


Figure 15. Capacitances

LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
 S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G

TYPICAL CHARACTERISTICS – LBC817-40LT1G

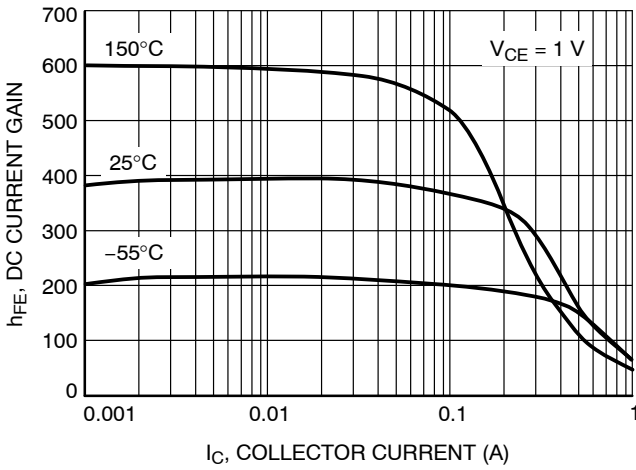


Figure 16. DC Current Gain vs. Collector Current

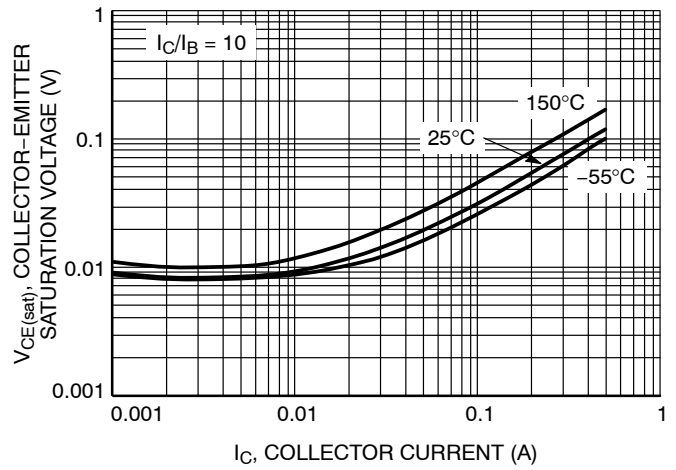


Figure 17. Collector Emitter Saturation Voltage vs. Collector Current

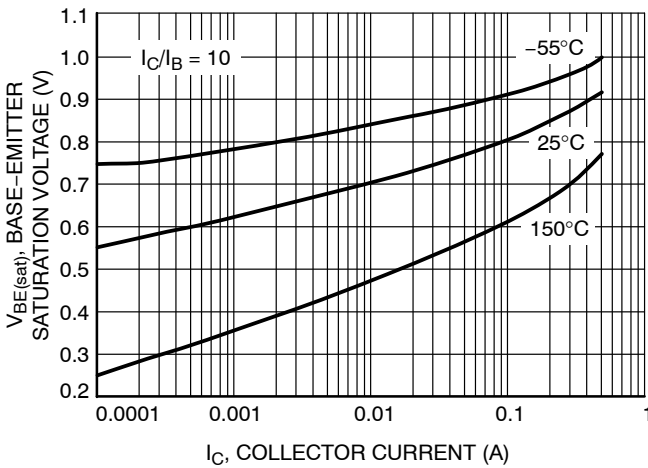


Figure 18. Base Emitter Saturation Voltage vs. Collector Current

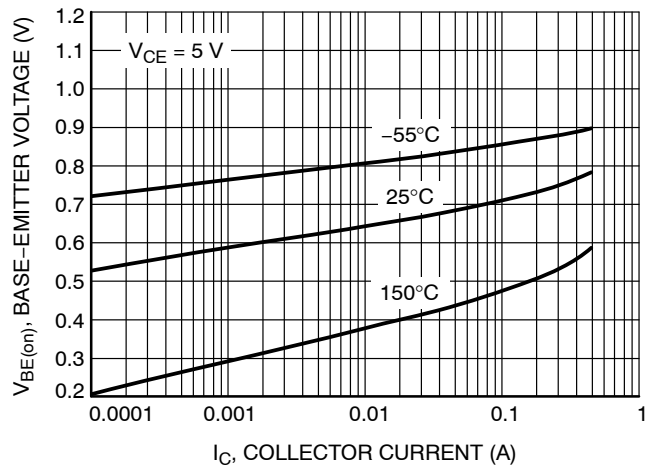


Figure 19. Base Emitter Voltage vs. Collector Current

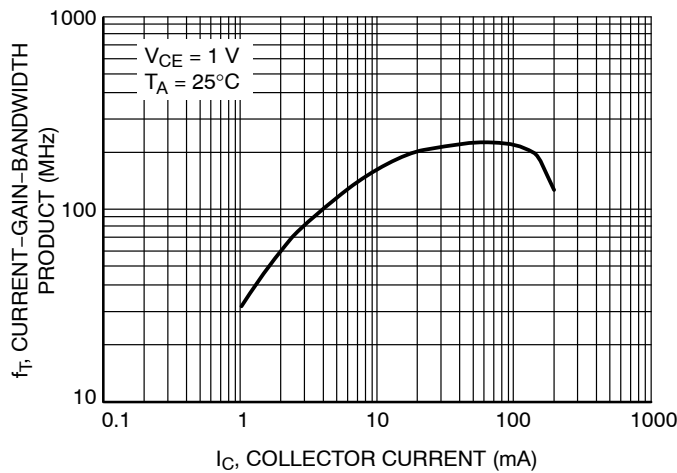


Figure 20. Current Gain Bandwidth Product vs. Collector Current

LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
 S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G

TYPICAL CHARACTERISTICS - LBC817-40LT1G

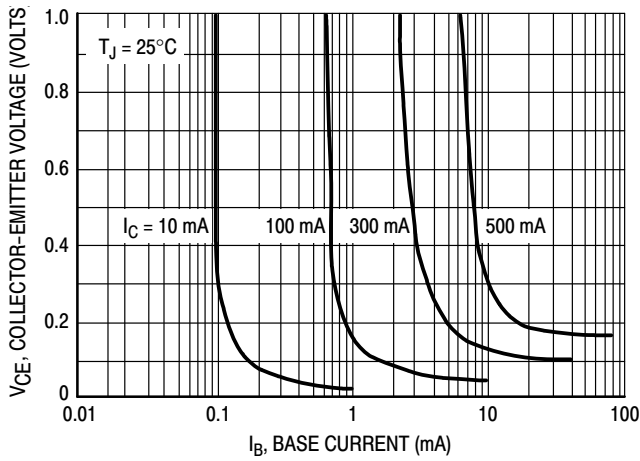


Figure 21. Saturation Region

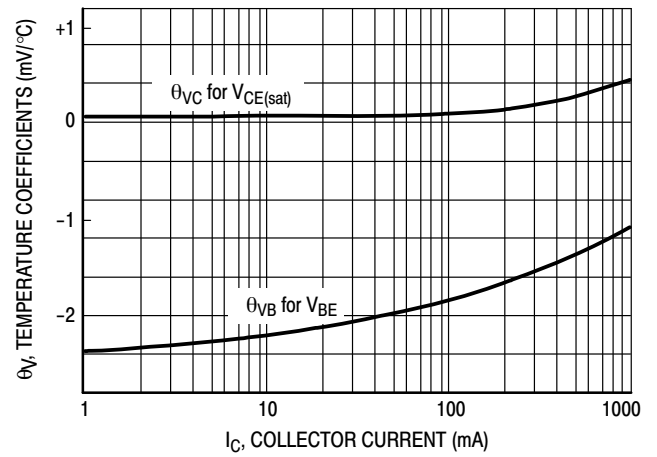


Figure 22. Temperature Coefficients

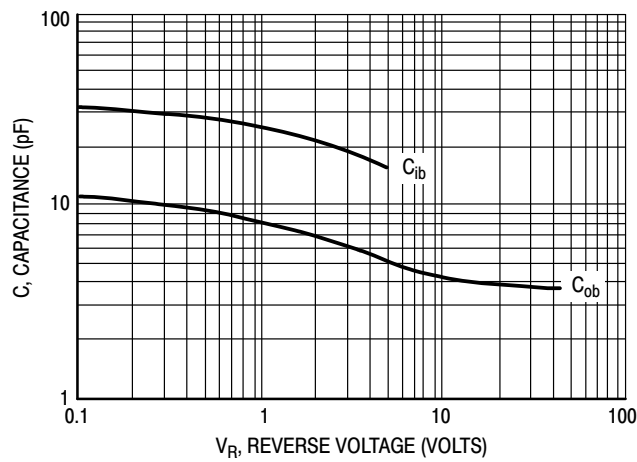


Figure 23. Capacitances

LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G

TYPICAL CHARACTERISTICS – LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G

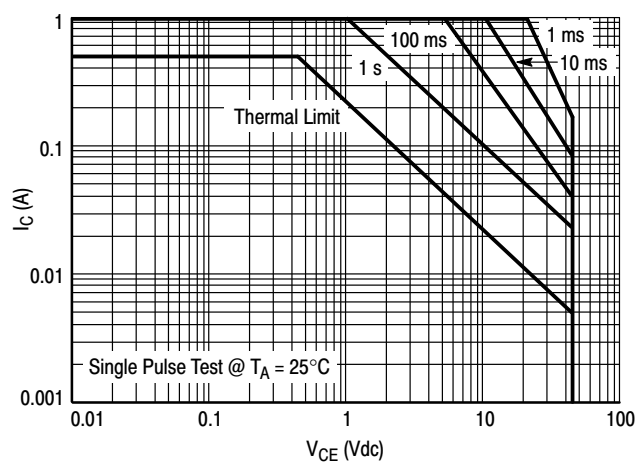
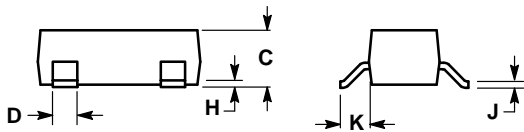
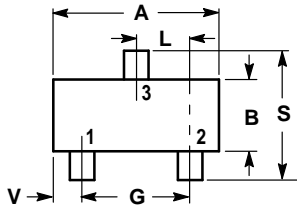


Figure 24. Safe Operating Area

LBC817-16LT1G LBC817-25LT1G LBC817-40LT1G
S-LBC817-16LT1G,S-LBC817-25LT1G,S-LBC817-40LT1G

SOT-23



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

- PIN 1. BASE
2. EMITTER
3. COLLECTOR

